



DMP3010LPSQ

### P-CHANNEL ENHANCEMENT MODE MOSFET PowerDI

## **Product Summary**

V <sub>(BR)DSS</sub>	R <sub>DS(ON)</sub>	Ι <sub>D</sub> T <sub>A</sub> = +25°C
-30V	$7.5 m\Omega @ V_{GS} = -10V$	-36A
-30 V	10mΩ @ V <sub>GS</sub> = -4.5V	-31A

## Description

This new generation 30V P-Channel Enhancement Mode MOSFET is designed to minimize  $R_{DS(ON)}$ , yet maintain superior switching performance. This device is ideal for use in notebook battery power management and loadswitch.

# **Applications**

- Notebook Battery Power Management
- DC-DC Converters
- Loadswitch

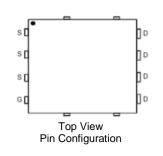
### Features

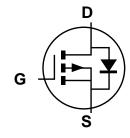
- Thermally Efficient Package Cooler Running Applications
- High Conversion Efficiency
- Low R<sub>DS(ON)</sub> Minimizes On-State Losses
- Low Input Capacitance
- Fast Switching Speed
- <1.1mm Package Profile Ideal for Thin Applications
- ESD HBM Protected up to 1kV
- Lead-Free Finish; RoHS Compliant (Notes 1 & 2)
- Halogen and Antimony Free. "Green" Device (Note 3)
- Qualified to AEC-Q101 Standards for High Reliability
- PPAP Available (Note 4)

### Mechanical Data

- Case: PowerDI<sup>®</sup>5060-8
- Case Material: Molded Plastic, "Green" Molding Compound. UL Flammability Classification Rating 94V-0
- Moisture Sensitivity: Level 1 per J-STD-020
- Terminal Connections: See Diagram Below
- Terminals: Finish 100% Matte Tin Annealed over Copper Leadframe. Solderable per MIL-STD-202, Method 208 (3)
- Weight: 0.097 grams (Approximate)







Internal Schematic

## Ordering Information (Note 5)

Part Number	Qualification	Case	Packaging
DMP3010LPSQ-13	Automotive	PowerDI5060-8	2,500/Tape & Reel

Notes: 1. EU Directive 2002/95/EC (RoHS) & 2011/65/EU (RoHS 2) compliant. All applicable RoHS exemptions applied.

2. See http://www.diodes.com/quality/lead\_free.html for more information about Diodes Incorporated's definitions of Halogen- and Antimony-free, "Green" and Lead-free.

3. Halogen- and Antimony-free "Green" products are defined as those which contain <900ppm bromine, <900ppm chlorine (<1500ppm total Br + Cl) and <1000ppm antimony compounds.

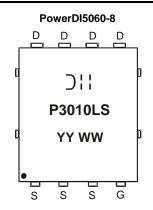
4. Automotive products are AEC-Q101 qualified and are PPAP capable. Refer to http://www.diodes.com/quality/product\_compliance\_definitions/.

5. For packaging details, go to our website at http://www.diodes.com/products/packages.html.

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# **Marking Information**



⊃!! = Manufacturer's Marking P3010LS = Product Type Marking Code YYWW = Date Code Marking YY = Year (ex: 15 = 2015) WW = Week (01 - 53)

# Maximum Ratings (@T<sub>A</sub> = +25°C, unless otherwise specified.)

Characteristi	Symbol	Value	Unit		
Drain-Source Voltage	V <sub>DSS</sub>	-30	V		
Gate-Source Voltage	V <sub>GSS</sub>	±20	V		
Continuous Drain Current (Note 8) $V_{GS}$ = 10V	Steady State	$T_A = +25^{\circ}C$ $T_A = +70^{\circ}C$	ID	-36 -29	А
Continuous Drain Current (Note 8) $V_{GS}$ = 4.5V	Steady State	T <sub>A</sub> = +25°C T <sub>A</sub> = +70°C	ID	-31 -25	A
Continuous Drain Current (Note 7) $V_{GS}$ = 10V	Steady State	$T_A = +25^{\circ}C$ $T_A = +70^{\circ}C$	I <sub>D</sub>	-14.5 -11.5	А
Pulsed Drain Current (Notes 7 & 10)	I <sub>DM</sub>	-100	A		
Avalanche Current (Notes 11 & 12)	I <sub>AS</sub>	-17.5	A		
Avalanche Energy (Notes 11 & 12) L = 1mH			E <sub>AS</sub>	153	mJ

## **Thermal Characteristics**

Characteristic	Symbol	Value	Unit
Power Dissipation (Note 6)	PD	1.26	W
Thermal Resistance, Junction to Ambient $@T_A = +25^{\circ}C$ (Note 6)	R <sub>0JA</sub>	97	°C/W
Power Dissipation (Note 7)	PD	2.18	W
Thermal Resistance, Junction to Ambient $@T_A = +25^{\circ}C$ (Note 7)	R <sub>0JA</sub>	55	°C/W
Power Dissipation (Note 8)	PD	14.37	W
Thermal Resistance, Junction to Ambient $@T_A = +25^{\circ}C$ (Note 8)	R <sub>0JA</sub>	8.7	°C/W
Power Dissipation (Notes 8 & 9)	PD	58.7	W
Thermal Resistance, Junction to Case @T <sub>C</sub> = +25°C (Notes 8 & 9)	R <sub>0JC</sub>	2.13	°C/W
Operating and Storage Temperature Range	TJ, T <sub>STG</sub>	-55 to +150	°C

6. Device mounted on FR-4 substrate PC board, 2oz copper, with minimum recommended pad layout. 7. Device mounted on FR-4 substrate PC board, 2oz copper, with 1inch square copper plate. Notes:

8. Device mounted on FR-4 PCB with infinite heatsink.

9.  $R_{\theta JC}$  is guaranteed by design while  $R_{\theta CA}$  is determined by the user's board design.

10. Repetitive rating, pulse width limited by junction temperature, 10µs pulse, duty cycle = 1%.

11. I<sub>AS</sub> and E<sub>AS</sub> rating are based on low frequency and duty cycles to keep  $T_J = +25^{\circ}C$ .



# Electrical Characteristics (@T<sub>A</sub> = +25°C, unless otherwise specified.)

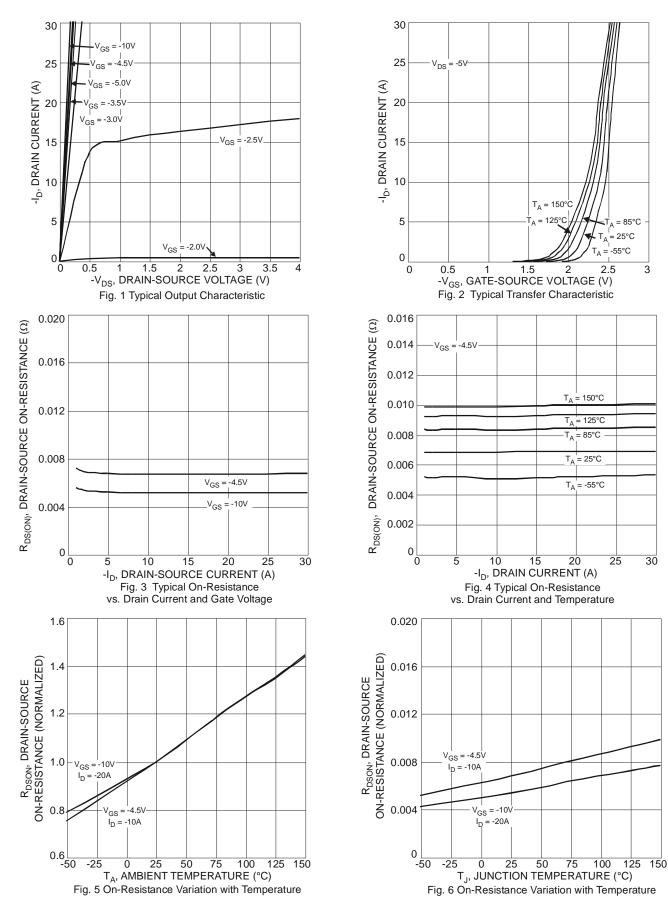
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Characteristic	Symbol	Min	Тур	Max	Unit	Test Condition	
OFF CHARACTERISTICS (Note 12)					r	-	
Drain-Source Breakdown Voltage	BV <sub>DSS</sub>	-30		—	V	$V_{GS} = 0V, I_D = -250 \mu A$	
Zero Gate Voltage Drain Current	IDSS	—		-1	μA	$V_{DS} = -30V, V_{GS} = 0V$	
Gate-Source Leakage	I <sub>GSS</sub>	—		±100	nA	$V_{GS} = \pm 20V, V_{DS} = 0V$	
ON CHARACTERISTICS (Note 12)							
Gate Threshold Voltage	V <sub>GS(th)</sub>	-1.1	-1.6	-2.1	V	$V_{DS} = V_{GS}, I_D = -250 \mu A$	
Static Drain-Source On-Resistance		—	5.7	7.5	mΩ	$V_{GS} = -10V, I_D = -10A$	
	R <sub>DS(ON)</sub>	—	7.2	10	11152	$V_{GS} = -4.5V, I_D = -10A$	
Forward Transfer Admittance	Y <sub>fs</sub>	—	30	_	S	$V_{DS} = -15V, I_D = -10A$	
Diode Forward Voltage	V <sub>SD</sub>	—	-0.65	-1	V	$V_{GS} = 0V, I_{S} = -1A$	
DYNAMIC CHARACTERISTICS (Note 13)							
Input Capacitance	Ciss	_	6,234	_	pF		
Output Capacitance	Coss	_	1,500	—	pF	− V <sub>DS</sub> = 15V, V <sub>GS</sub> = 0V, − f = 1MHz	
Reverse Transfer Capacitance	C <sub>rss</sub>	_	774	-	pF	1 = 101112	
Gate Resistance	Rg	_	1.28	_	Ω	$V_{DS} = 0V$ , $V_{GS} = 0V$ , $f = 1MHz$	
Total Gate Charge (V <sub>GS</sub> = -10V)	Qg	_	126.2	_	nC	$V_{DS} = -15V, I_D = -10A$	
Total Gate Charge (V <sub>GS</sub> = -4.5V)	Qg	—	59.2	_	nC	V <sub>DS</sub> = -15V, V <sub>GS</sub> = -4.5V, -1 <sub>D</sub> = -10A	
Gate-Source Charge	Q <sub>gs</sub>	_	16.1		nC		
Gate-Drain Charge	Q <sub>gd</sub>	_	15.7		nC		
Turn-On Delay Time	t <sub>D(on)</sub>	_	11.4	—	ns		
Turn-On Rise Time	tr	_	9.4	_	ns	V <sub>DS</sub> = -15V, V <sub>GEN</sub> = -10V,	
Turn-Off Delay Time	t <sub>D(off)</sub>	_	260.7	—	ns	$R_G = 6\Omega, I_D = -1A$	
Turn-Off Fall Time	t <sub>f</sub>	—	99.3		ns	7	

 Short duration pulse test used to minimize self-heating effect.
Guaranteed by design. Not subject to product testing. Notes:

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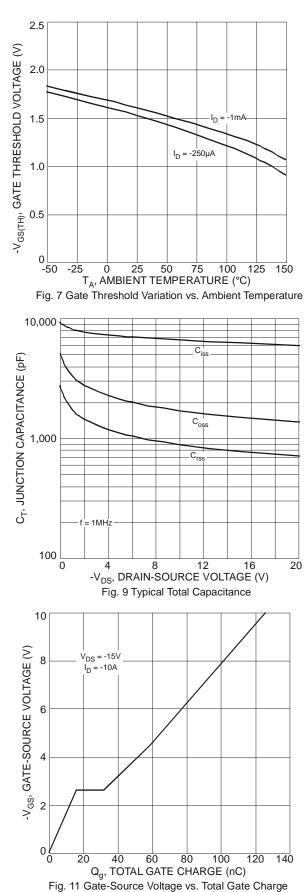
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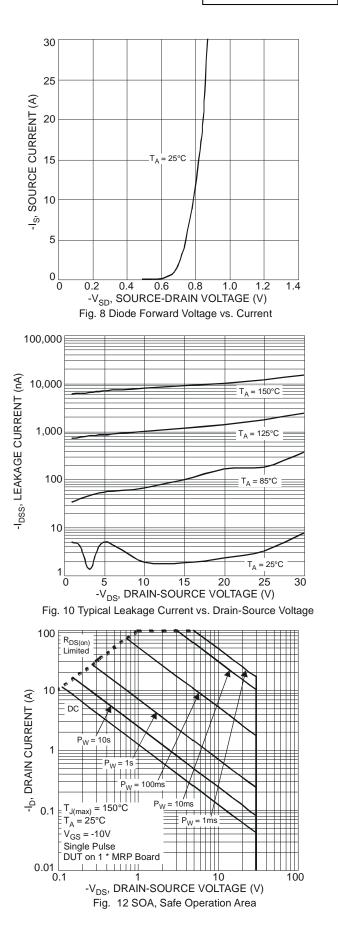




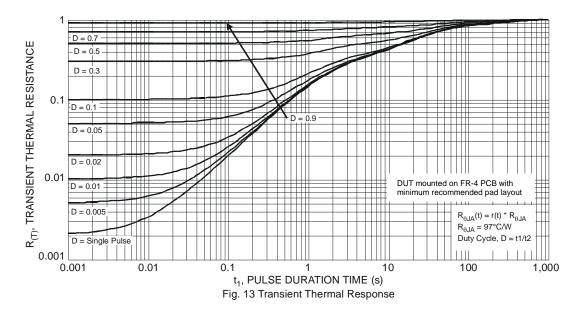
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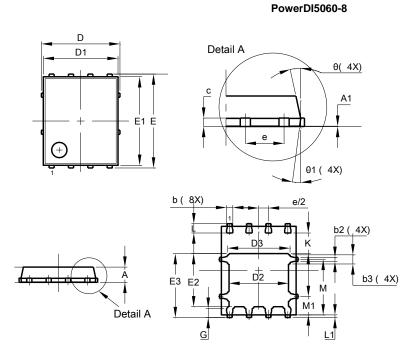






# **Package Outline Dimensions**

Please see AP02002 at http://www.diodes.com/datasheets/ap02002.pdf for the latest version.

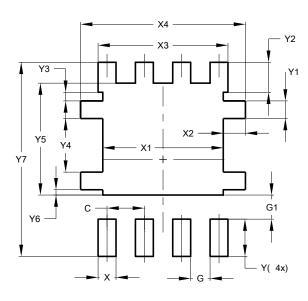


PowerDI5060-8					
Dim	Min	Max	Тур		
Α	0.90	1.10	1.00		
A1	0.00	0.05	-		
b	0.33	0.51	0.41		
b2	0.200	0.350	0.273		
b3	0.40	0.80	0.60		
c	0.230	0.330	0.277		
D		5.15 BSC	;		
D1	4.70	5.10	4.90		
D2	3.70	4.10	3.90		
D3	3.90	4.30	4.10		
E	(	6.15 BSC	;		
E1	5.60	6.00	5.80		
E2	3.28	3.68	3.48		
E3	3.99	4.39	4.19		
е	1.27 BSC				
G	0.51	0.71	0.61		
ĸ	0.51	-	-		
L	0.51	0.71	0.61		
L1	0.100	0.200	0.175		
М	3.235	4.035	3.635		
M1	1.00	1.40	1.21		
Θ	10°	12°	11°		
Θ1	6°	8°	7°		
Al	All Dimensions in mm				

# Suggested Pad Layout

Please see AP02001 at http://www.diodes.com/datasheets/ap02001.pdf for the latest version.

PowerDI5060-8



Dimensions	Value (in mm)
С	1.270
G	0.660
G1	0.820
Х	0.610
X1	4.100
X2	0.755
X3	4.420
X4	5.610
Y	1.270
Y1	0.600
Y2	1.020
Y3	0.295
Y4	1.825
Y5	3.810
Y6	0.180
Y7	6.610



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